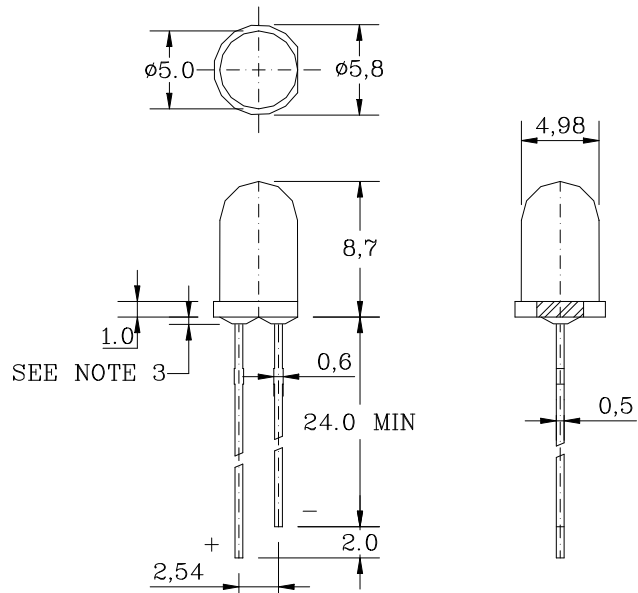


Features

- ◆ High intensity
- ◆ Standard T-1 diameter type package
- ◆ General purpose leads
- ◆ Reliable and rugged

Package Dimension:



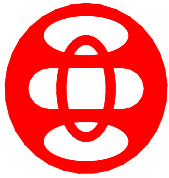
Part No.	Chip Material	Lens Color	Source Color
504WC	InGaN/GaN	Water clear	White

Notes:

1. All dimensions are in millimeters.
2. Tolerance is ± 0.25 mm unless otherwise noted.
3. Protruded resin under flange is 1.0mm max.

Approved By:

Designed By: 黄国英



深圳市成光兴实业发展有限公司

SHENZHEN CHENGGUANGXING INDUSTRIAL DEVELOPMENT CO.,LTD.

Absolute Maximum Ratings at Ta=25°C

Parameter	MAX	Unit
Power Dissipation	120	mW
Peak Forward Current (1/10 Duty Cycle,0.1ms Pulse Width)	100	mA
Continuous Forward Current	30	mA
Reverse Voltage	5	V
Electrostatic Discharg(ESD)	300	V
Operating Temperature Range	-25°C to +80°C	
Storage Temperature Range	-25°C to +85°C	
Lead Soldering Temperature (4mm From Body)	260°C for 5 seconds	

Electrical Optical Characteristics at Ta=25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Luminous Intensity	I _v	10000	12000	----	mcd	I _F =20mA(Note 1)
Viewing Angle	2 θ _{1/2}	----	15	-----	Deg	(Note 2)
Chromaticity Coordinates	x	-----	0.30	----		I _F =20mA
	y	-----	0.30	----		
Forward Voltage	V _F	2.8	3.2	3.6	V	I _F =20mA
Reverse Current	I _R	----	----	10	μ A	V _R =5V

Note:

1. Luminous intensity is measured with a light sensor and filter combination that approximates the CIE eye-response curve.
2. θ_{1/2} is the off-axis angle at which the luminous intensity is half the axial luminous intensity.